A terraced scanning superconducting quantum interference device susceptometer with submicron pickup loops

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Superconducting quantum interference devices (SQUIDs) can have excellent spin sensitivity depending on their magnetic flux noise, pickup loop diameter, and distance from the sample. We report a family of scanning SQUID susceptometers with terraced tips that position the pickup loops 300 nm from the sample. The 600 nm−2 μm pickup loops, defined by focused ion beam, are integrated into a 12-layer optical lithography process allowing flux-locked feedback, in situ background subtraction and optimized flux noise. These features enable a sensitivity of ∼70 electron spins per root hertz at 4 K. © 2008 American Institute of Physics.

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In 1989, Ketchen et al.,1 argued that the advent of submicron lithography should enable superconducting quantum interference devices (SQUIDs) with single electron spin sensitivity. Stationary devices can measure nanomagnets with great success,5 but it remains difficult, even with the highest spin sensitivity SQUIDs,3 to detect single-molecule field sources. Scanning devices4–9 make it possible to isolate magnetic field sources and to perform background measurements in situ.10 Single-layer scanning nano-SQUIDs (Ref. 7) have not yet achieved the excellent flux sensitivity of the best large multilayer SQUIDs. Multilayer SQUIDs thus far have had large pickup areas that do not capture dipole field lines well, thereby limiting the spin sensitivity of these devices. For a normal-oriented dipole on the center line of a pickup loop of radius R, the spin sensitivity, $S_n$, is

$$S_n(\mu_B/\text{Hz}) = \Phi_{p} R^3 \left(1 + \frac{h^2}{R^2}\right)^{3/2},$$

where $\Phi_p$ is the flux noise in units of $\Phi_0/\sqrt{\text{Hz}}$, h is the pickup loop’s height above the sample, and $r_p = 2.82 \times 10^{-15}$ m.1 On the center line, near-optimal signal is achieved for $h < R$. The spin sensitivity can be further improved by placing the dipole near the edge of the pickup loop, although demagnetization limits this enhancement for $h < w$, where w is the linewidth. For simplicity, we use Eq. (1) to compare representative published scanning SQUIDs (Table I).

Our scanning SQUID combines focused ion beam (FIB) defined pickup loops with a 12-layer optical lithography process that includes local field coils. Integrated terraces minimize h. We characterize the imaging kernel with a superconducting vortex and a dipole field source. Flux noise measurements at 4 K demonstrate a spin sensitivity of ∼70$\mu_B/\sqrt{\text{Hz}}$. Flux noise may decrease at lower temperatures9,13 leading to a projected sensitivity of ∼15$\mu_B/\sqrt{\text{Hz}}$.

Our susceptometer incorporates two symmetric counter-wound arms, each with an integrated modulation loop, pickup loop, and local field coil [Fig. 1(a)]. A three metallization layer, linear coaxial transmission line geometry shields the device from magnetic fields. The transmission line geometry has a low inductance per unit length (∼10 pH/mm), which allows for a large separation between the feedback/junction area and the two pickup loops without significantly increasing the devices theoretical white noise floor.14 The separation permits the use of standard, well optimized junction and resistive shunt fabrication processes.15 The resistive shunts ensure a nonhysteretic response. The scanning SQUID is voltage biased and its current is amplified with a SQUID series array (SSA) amplifier.16 A feedback circuit controls the current in the modulation loop, responding to the SSA output voltage to create a flux locked loop. Feedback linearizes the signal and allows for optimal sensitivity at all applied fields. The field coils aid background subtraction.9 By applying a local field to the sample only in the area of the pickup loop, the field coils also allow for a

**Table I.** Survey of reported scanning SQUIDs and estimated spin sensitivity for $h=0$ [Eq. (1)]. With one exception, (Ref. 7) the corners are typically 20–60 μm from the pickup loop, likely limiting h to 1–3 μm. For rectangular loops, we use $R=(l/r_c/\pi)^{1/2}$.

<table>
<thead>
<tr>
<th>Principal investigator</th>
<th>Year</th>
<th>Size ($\mu^2$)</th>
<th>Flux Noise ($\mu B/\sqrt{\text{Hz}}$)</th>
<th>Spin Sensitivity ($\mu B/\sqrt{\text{Hz}}$)</th>
</tr>
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<td>Vu et al.4,6</td>
<td>1993</td>
<td>100</td>
<td>3</td>
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<td>2</td>
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<td>8</td>
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<td>640</td>
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<td>0.3</td>
<td>0.7</td>
<td>74</td>
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</tbody>
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low magnetic field environment near the junction, modulation, and amplification stages.

To achieve optimal flux noise, each junction’s critical current, $I_C$, is approximately half the superconducting flux quantum, $\Phi_0/2$, divided by the SQUID’s self inductance, $L$. At 4 K, we have a $0.7\mu\Phi_0/\sqrt{\text{Hz}}$ noise floor above 300 Hz and $1.2\mu\Phi_0/\sqrt{\text{Hz}}$ 1/f-like noise at 10 Hz [Fig. 2(f)]. If the dominant flux noise is Johnson noise in the shunt resistors, as indicated by $T^{1/2}$ temperature dependence in a previous similar device, a white noise floor of $0.25\mu\Phi_0/\sqrt{\text{Hz}}$ may be achievable at 300 mK. Cooling fins attached to the shunt resistors of some devices to minimize the effect of electron-phonon coupling limited cooling may enable a white noise floor of $0.12\mu\Phi_0/\sqrt{\text{Hz}}$ at dilution refrigerator temperatures.

When limited by the Johnson noise in resistive shunts, the theoretical flux noise dependence scales like $L^{3/2}$, whereas quantum noise scales like $L^{1/2}$. The incentive for a well quantified low inductance adds to the criteria for optimal pickup loop design. When the width, $w$, or the thickness, $t$, of a superconducting feature becomes smaller than the penetration depth, $\lambda$, kinetic inductance can overcome the geometrical inductance contribution and scales like $L_k \propto \lambda^2/wt$. Thus, linewidths smaller than $\lambda$ are undesirable. This effect, along with phase winding considerations related to coherence length effects, ultimately sets the pickup loop size limit. Inductance also scales with feature length so we have kept the submicron portion of the leads short, just long enough to allow the pickup loop to touch down first without excessive stray pickup.

For optimal coupling, a dipole on the center line of the pickup loop should have $h<R$, while a dipole near the edge of the pickup loop should have $h<w$. Figure 1(b) shows an optically defined, $w=0.6\mu m$, $3.2\mu m$ diameter, pickup loop pattern with etch features inside and outside the field coil. The outer etch supplements hand polishing to bring the corner of the chip close to the field coil, and the inner etch reduces the oxide layer above the field coil. The thickness of the multiple layers is important parts of the design. In Fig. 1(b), the pickup loop is under 250 nm of SiO$_2$ as required for a top layer of shielding. It is thus at least this distance from the surface. The well created by the circular field coil allows little tolerance from the optimal alignment angle of 2.5° [inset, Fig. 1(b)]. Additionally, it is difficult to align the device such that the off-center field coil leads do not touch down first. While the SiO$_2$ layer and limited alignment tolerance is suitable for the $w$ and $R$ of the optically patterned design, these effects are detrimental for submicron pickup loops.

We explored several techniques to create superconducting submicron pickup loops integrated with the multilayer structure: e-beam defined lift-off lithography with Al, e-beam lithography for etching optically patterned Nb layers, and FIB etching of optically patterned Nb layers. The FIB etching was the most tractable. We also found that sputtered Nb has a smaller penetration depth (~90 nm) than e-beam evaporated Al patterned with polymethyl methacrylate lift-off (~120–160 nm), allowing for smaller linewidths and reduced the calculated inductance for a pair of pickup loops (22 versus 66 pH). The inductance of the rest of the design is
60–65 pH. Here, we only report results from optically and FIB defined Nb tips.

Our FIB design uses three superconducting layers [Fig. 1(c)] such that the field coil lines (gray) run underneath a shielding layer (purple) and approach the tip from the same angle as the pickup loop. The pickup loop on the top layer (green) is closest to the sample, which also allows for postoptical FIB processing. This design allows the pickup loop to touch first when the SQUID is aligned to a pitch angle of 2°–5° [Fig. 1(c), inset], with a roll tolerance equal to the pitch angle. To increase durability, we fabricated some devices with the pickup loop retracted from the end of the etch-defined SiO₂ tab [Fig. 1(d)], allowing the SiO₂ to take the brunt of the wear. The SiO₂ tab also overlaps with the inside edge of the field coil, making a high point that protects the pickup loop retracted from the end of the etch-defined SiO₂ tab.

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Fitting a simple model of the pickup loop response to the vortex and dipole [Figs. 2(b)–2(g)] gives an effective h. The vortex model is a monopole field source one penetration depth (h_{eff} = 150 nm) below the surface. The dipole model is a free-space dipole field source at the surface. The field from each of these two sources is integrated over the model is a free-space dipole field source at the surface. The alignment angle is difficult to set accurately and can change due to thermal contractions, so these considerations are important for protecting the device.

We imaged Sr₂RuO₄ (Fig. 2) to characterize the FIB defined device’s coupling to a sample. Flux from a monopolelike superconducting vortex can couple through both the pickup loop and its leads [Fig. 2(a)]. Our smallest SQUIDs are designed to do comparative studies on and off a particular mesoscopic structure, rather than provide a pointlike imaging kernel.

Calculations from relevant line midpoints.

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12 Fitting a simple model of the pickup loop response to the vortex and dipole [Figs. 2(b)–2(g)] gives an effective h. The vortex model is a monopole field source one penetration depth (h_{eff} = 150 nm) below the surface. The dipole model is a free-space dipole field source at the surface. The field from each of these two sources is integrated over the effective pickup loop area at an effective height h_{eff} = 400 nm. This h_{eff} implies that the closest side of the 200 nm thick pickup loop is 300 nm above the scanned surface. Several effects could make this estimate of h larger than the physical distance from the sample, such as the existence of a Meissner image dipole, \lambda_{Sr_2RuO_4} > 150 nm due to dead layers or finite T, and demagnetization effects from the thickness of the pickup loop.
13 In conclusion, we have demonstrated SQUIDs with 0.7μΦ₀/\hbar Hz flux noise at 4 K, reliable FIB pickup loops with diameters as small as 600 nm, and a terraced geometry that allows the pickup loop to come within 300 nm of the surface. These features give a spin sensitivity of ~70μB/\hbar Hz, that is, the device noise is equivalent to the signal from a single electron spin after an averaging time of a little more than one hour. At lower temperatures a lower flux noise is likely, leading to spin sensitivities less than 15μB/\hbar Hz.

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11 Calculations from relevant line midpoints.
12 Flux noise at 4.2 K.
13 See EPAPS Document No. E-APPLAB-93-013850 for information on the FIB fabrication, layer thickness effects, and shunt-resistor cooling fins. For more information on EPAPS, see http://www.aip.org/pubservs/epaps.html.